


	<p>IPD082N10N3GBTMA1</p>
	<p>Manufacturer Part Number: IPD082N10N3GBTMA1</p> <p>Manufacturer/Brand: International Rectifier (Infineon Technologies)</p> <p>Part of Description: MOSFET N-CH 100V 80A TO252-3</p> <p>Datasheets:  IPD082N10N3GBTMA1.pdf</p> <p>RoHS Status:  Lead free / RoHS</p> <p>Stock Condition: Compliant New original, Stock Available.</p> <p>Ship From: Hong Kong</p> <p>Shipment Way: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Specifications








Part Number	IPD082N10N3GBTMA1
Manufacturer	International Rectifier (Infineon Technologies)
Description	MOSFET N-CH 100V 80A TO252-3
Category	Discrete Semiconductor Products > Transistors - FETs,
Part Status	Require For Quote & Check Stock
Vgs(th) (Max) @ Id	3.5V @ 75µA
Technology	MOSFET (Metal Oxide)
Supplier Device Package	PG-TO252-3
Series	OptiMOS™
Rds On (Max) @ Id, Vgs	8.2 mOhm @ 73A, 10V
Power Dissipation (Max)	125W (Tc)
Packaging	Tape & Reel (TR)
Package / Case	TO-252-3, DPak (2 Leads + Tab), SC-63
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Surface Mount
Input Capacitance (Ciss) (Max) @ Vds	3980pF @ 50V
Gate Charge (Qg) (Max) @ Vgs	55nC @ 10V
FET Type	N-Channel
FET Feature	-
Drain to Source Voltage (Vdss)	100V
Current - Continuous Drain (Id) @ 25°C	80A (Tc)

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